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**BOX AF**

AF/2828  
#3  
Amended  
6/22/02

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **OHSAKA, et al.**

Group Art Unit: 2828

Serial No.: **09/456,531**

Examiner: **James A. Menefee**

Filed: **December 8, 1999**

Confirmation No. 6582

**FOR: ELECTRODE STRUCTURE, PROCESS FOR FABRICATING ELECTRODE  
STRUCTURE AND SEMICONDUCTOR LIGHT-EMITTING DEVICE**

**AMENDMENT UNDER 37 CFR §1.116**  
**- EXPEDITED RESPONSE -**  
**GROUP ART UNIT 2828**

**BOX AF**

Commissioner for Patents  
Washington, D.C. 20231

June 19, 2002

Sir:

In response to the Office Action dated **March 25, 2002**, please amend the above-identified application as follows:

**CLEAN VERSION OF AMENDMENTS**  
**IN THE CLAIMS**

Please amend claims 1-3, 5, 7, 8, 13 and 14 as follows:

1. (Amended) An electrode structure including a conductive film formed on an insulation film, the insulation film being formed on a base substrate,  
  
the insulation film comprising a plurality of poles of polyimide, a first film formed on side surfaces of the poles and formed of an insulation material having a higher hardness than polyimide, and a second film of polyimide buried among said a plurality of poles with the first film formed on the side surfaces thereof.

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